



2SC1815

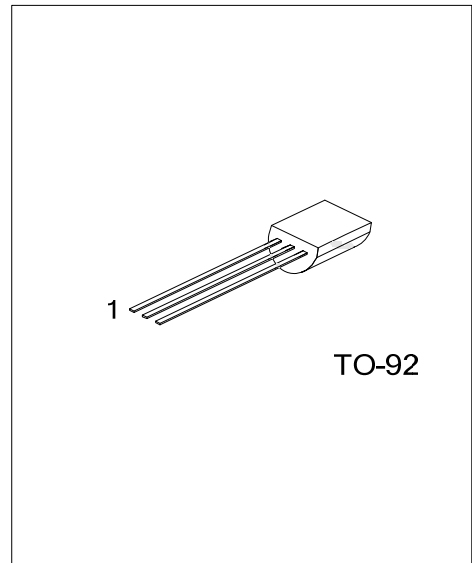
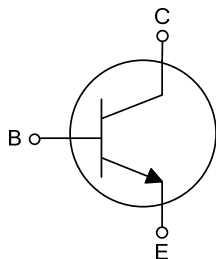
NPN SILICON TRANSISTOR

AUDIO FREQUENCY
AMPLIFIER HIGH
FREQUENCY OSC NPN
TRANSISTOR

FEATURES

- * Collector-Emitter voltage:
 $BV_{CEO}=50V$
- * Collector current up to 150mA
- * High h_{FE} linearity
- * Complimentary to UTC 2SA1015

SYMBOL



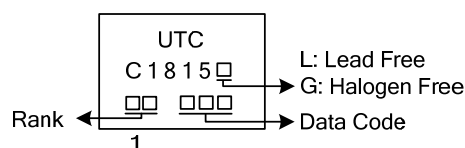
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2SC1815L-xx-T92-B	2SC1815G-xx-T92-B	TO-92	E	C	B	Tape Box
2SC1815L-xx-T92-K	2SC1815G-xx-T92-K	TO-92	E	C	B	Bulk

Note: Pin Assignment: E: Emitter C: Collector B: Base

2SC1815L-xx-T92-B (1) Packing Type (2) Package Type (3) Rank (4) Green Package	(1) B: Tape Box, K: Bulk (2) T92: TO-92 (3) xx: Refer to Classification of h_{FE1} (4) L: Lead Free, G: Halogen Free and Lead Free
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MARKING



■ ABSOLUTE MAXIMUM RATING ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	60	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_{C}	150	mA
Base Current	I_{B}	50	mA
Power Dissipation ($T_A=25^{\circ}\text{C}$)	P_{D}	625	mW
Junction Temperature	T_{J}	+125	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55 ~ +125	$^{\circ}\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ_{JC}	80	$^{\circ}\text{C/W}$

■ ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-off Current	I_{CBO}	$V_{\text{CB}}=60\text{V}$, $I_{\text{E}}=0$			100	nA
Emitter Cut-off Current	I_{EBO}	$V_{\text{EB}}=5\text{V}$, $I_{\text{C}}=0$			100	nA
Collector-Emitter Saturation Voltage	$V_{\text{CE(SAT)}}$	$I_{\text{C}}=100\text{mA}$, $I_{\text{B}}=10\text{mA}$		0.1	0.25	V
Base-Emitter Saturation Voltage	$V_{\text{BE(SAT)}}$	$I_{\text{C}}=100\text{mA}$, $I_{\text{B}}=10\text{mA}$			1.0	V
DC Current Gain	h_{FE1}	$V_{\text{CE}}=6\text{V}$, $I_{\text{C}}=2\text{mA}$	70		700	
	h_{FE2}	$V_{\text{CE}}=6\text{V}$, $I_{\text{C}}=150\text{mA}$	25			
Current Gain Bandwidth Product	f_{T}	$V_{\text{CE}}=10\text{V}$, $I_{\text{C}}=50\text{mA}$	80			MHz
Output Capacitance	C_{ob}	$V_{\text{CB}}=10\text{V}$, $I_{\text{E}}=0$, $f=1\text{MHz}$		2.0	3.0	pF

■ CLASSIFICATION OF h_{FE1}

RANK	O	Y	GR	BL
RANGE	70~140	120~240	200~400	350~700

■ TYPICAL CHARACTERISTICS

Fig.1 Static characteristics

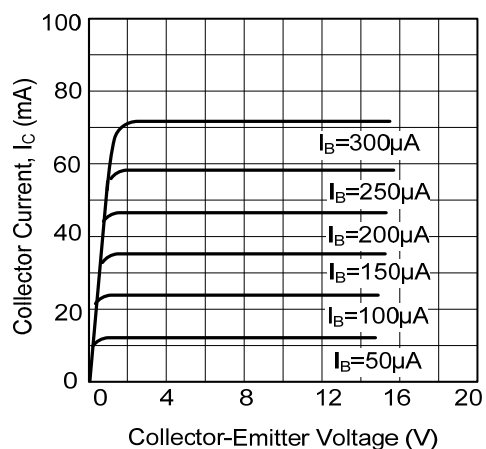


Fig.2 DC current Gain

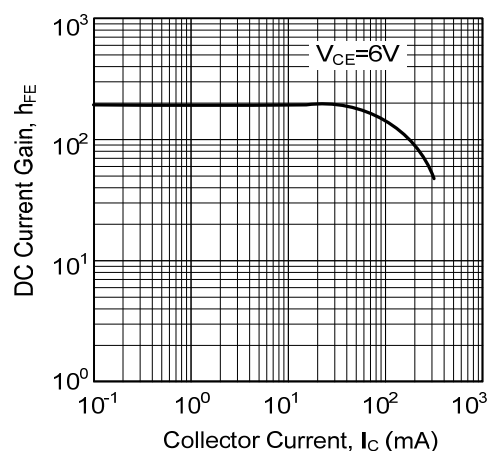


Fig.3 Base-Emitter on Voltage

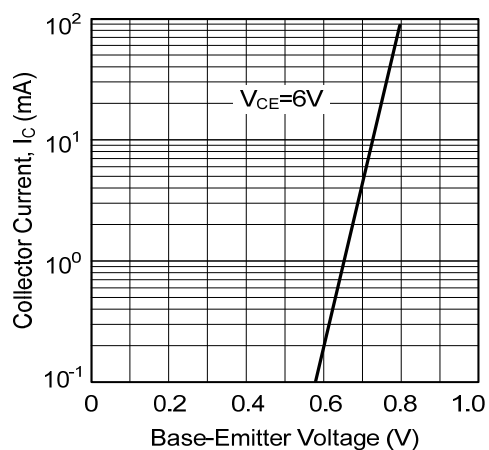


Fig.4 Saturation Voltage

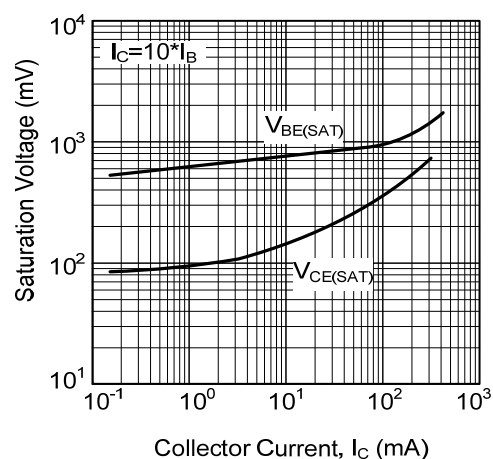


Fig.5 Current Gain-Bandwidth Product

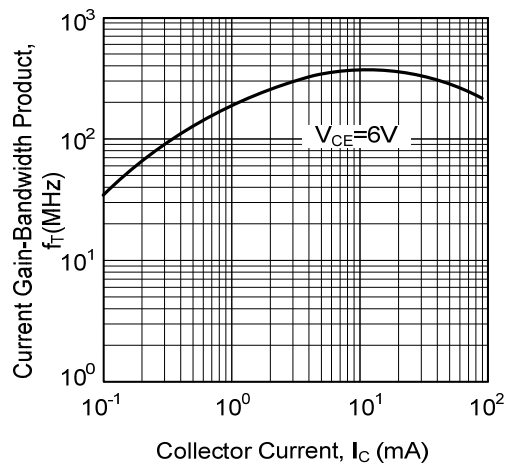
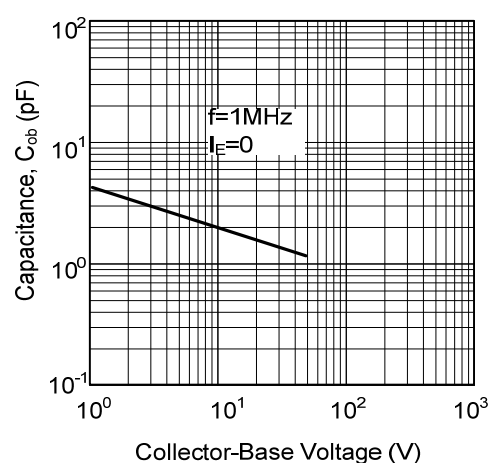
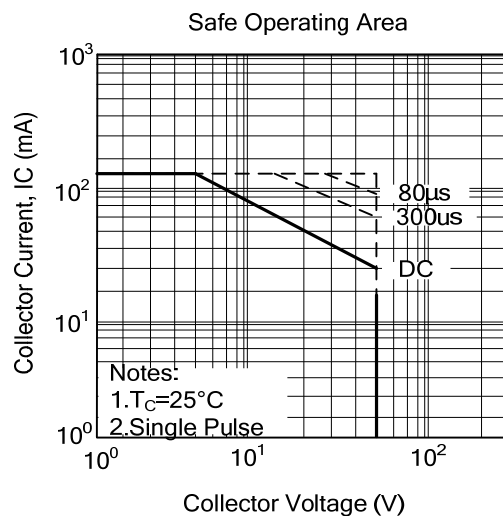


Fig.6 Collector Output Capacitance



■ TYPICAL CHARACTERISTICS(Cont.)



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